General Description

The MAX8594/MAX8594A complete power-management chips for low-cost personal digital assistants (PDAs) operates from a 1-cell lithium-ion (Li+) or 3-cell NiMH battery. They include all regulators, outputs, and voltage monitors necessary for small portable devices while requiring a bare minimum of external components. Featured are three linear regulators, a boost DC-DC converter for LCD bias, an efficient 4MHz buck DC-DC converter for core power, a microprocessor (μ P) reset output, and low-battery shutdown in a 0.8mm high thin QFN package.

The COR1 buck DC-DC converter supplies a pin-selectable output at 400mA. All linear regulators feature PMOS pass elements for efficient low-dropout operation. A MAIN LDO supplies 3.3V at 500mA. A securedigital (SD) card slot output supplies 3.3V at 500mA, and a COR2 LDO supplies 1.8V at 50mA. Each output has its own logic-controlled enable. For other output voltage combinations, contact Maxim.

An LCD bias boost DC-DC converter features an onboard MOSFET and True Shutdown[™] when off. This means that during shutdown, input power is disconnected from the inductor so the boost output falls to 0V rather than remaining one diode drop below the input voltage.

A μ P reset output clears 20ms (typ) after the COR1 output achieves regulation to ensure an orderly start. In addition, the COR1 regulator is not started until the 3.3V main output is in regulation. Also included are a 1% accurate reference and low-battery monitor. Thermal shutdown protects the die from overheating.

The MAX8594/MAX8594A operate from a 3.1V to a 5.5V supply voltage and consume 46μ A no-load supply current. They are packaged in a tiny, 4mm x 4mm, 24-pin thin QFN capable of dissipating 1.67W. The devices are specified for operation from -40°C to +85°C.

Applications

PDAs Organizers Cellular and Cordless Phones MP3 Players Handheld Devices

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX8594ETG	-40°C to +85°C	24 Thin QFN-EP* 4mm x 4mm (T2444-4)
MAX8594AETG	-40°C to +85°C	24 Thin QFN-EP* 4mm x 4mm (T2444-4)

*EP = Exposed pad.

Features

- Minimum External Components
- Efficient Step-Down DC-DC Powers CPU Core
- 1V/1.3V Selectable Core Voltage, 400mA (MAX8594)
- 1.3V/1.8V Selectable Core Voltage, 400mA (MAX8594A)
- Main LDO 3.3V, 500mA
- SD Card Output 3.3V, 500mA
- Second Core LDO 1.8V, 50mA
- High-Efficiency LCD Boost
- ♦ LCD 0V True Shutdown when Off
- ♦ 46µA Quiescent Current

Typical Operating Circuit



Pin Configuration appears at end of the data sheet. True Shutdown is a trademark of Maxim Integrated Products, Inc.

_ Maxim Integrated Products 1

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

ABSOLUTE MAXIMUM RATINGS

IN, PV, ENSD, ENC1, ENC2, ENL, RS, SDIG,	Current into LXC
LBI, DBI to GND0.3	.3V to +6V Output Short-Circuit Durat
LXL to GND0.3	V to +30V Continuous Power Dissipa
MAIN, COR1, COR2, REF, LFB, CV, ENM, LBO, DBO,	24-Pin Thin QFN Packa
LXC, SW to GND0.3V to (VI	(derate 20.8mW/°C abo
PV to IN0.3V	
PGND to GND0.3V	V to +0.3V Junction Temperature
Current into LXL	00mA _{BMS} Storage Temperature Ran
Current out of SW	00mA _{RMS} Lead Temperature (solder

Output Short-Circuit Duration	Continuous
Continuous Power Dissipation ($T_A = +70^{\circ}$ C	C)
24-Pin Thin QFN Package	
(derate 20.8mW/°C above +70°C)	1.67W
Operating Temperature Range	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

100m 1 ----

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{IN} = V_{PV} = V_{ENSD} = V_{ENC2} = V_{ENL} = V_{ENM} = V_{ENC1} = V_{DBI} = V_{LBI} = V_{CV} = 4.0V$, $T_A = 0^{\circ}C$ to +85°C, unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
GENERAL						
IN, PV Voltage Range		3.1		5.5	V	
V _{IN} Complete Shutdown Threshold	V _{DBI} = V _{IN} , V _{IN} falling	2.950	3.0	3.050	V	
	$V_{DBI} = V_{IN}, V_{IN}$ rising	3.135	3.3	3.525	v	
V _{DBI} Complete Shutdown	V _{DBI} falling	1.234	1.25	1.263	V	
Threshold	V _{DBI} rising	1.306	1.375	1.478	v	
V _{LBI} LBO Threshold	V _{LBI} rising	1.234	1.25	1.263	V	
VLBI CBO THIESHOLD	V _{LBI} falling	1.103	1.125	1.140	v	
VIN LBO Threshold	$V_{LBI} = V_{IN}, V_{IN}$ falling	3.262	3.33	3.366	V	
	$V_{LBI} = V_{IN}, V_{IN}$ rising	3.625	3.7	3.744	v	
	Preset mode, V _{IN} = 2.9V	V _{IN} - 0.3				
DBI Input Dual Mode™ Threshold	ADJ mode, V _{IN} = 2.9V			V _{IN} - 1.2	V	
LBI Input Dual-Mode Threshold	Preset mode, V _{IN} = 3.2V	V _{IN} - 0.3			.,	
with Respect to IN	ADJ mode, V _{IN} = 3.2V			V _{IN} - 1.2	V	
DBI Complete Shutdown Input Program Range	V _{IN} falling	3.0		5.5	V	
DBI Input Bias Current	V _{DBI} = 1.25V	-50		+50	nA	
LBI Input Bias Current	V _{LBI} = 1.25V	-50		+50	nA	
	Shutdown (DBI remains on, REF off), $V_{IN} = V_{PV} = V_{DBI} = V_{LBI} = 2.7V$		2	10		
IN, PV Operating Current	All off (REF on)		30	55	μA	
	All on; LXL, LXC not switching		130	180		
	Main on, no load		46	75		
IN Operating Current	Main on, no load, COR1 on, LXC not switching		80	110	μΑ	
	All on except LCD, $V_{ENL} = 0V$, LXL and LXC not switching		115	160	7	

Dual Mode is a trademark of Maxim Integrated Products, Inc.



ELECTRICAL CHARACTERISTICS (continued)

 $(V_{IN} = V_{PV} = V_{ENSD} = V_{ENC2} = V_{ENL} = V_{ENM} = V_{ENC1} = V_{DBI} = V_{LBI} = V_{CV} = 4.0V$, **T_A = 0°C to +85°C**, unless otherwise noted. Typical values are at T_A = +25°C.)

PARAMETER	CONDITIONS	MIN	ΤΥΡ	MAX	UNITS
LDOs					
MAIN, SDIG Soft-Start Time		300	600	1200	μs
MAIN Output Voltage	I _{LOAD} = 100µA to 300mA, V _{IN} = 3.6V to 5.5V	3.218	3.3	3.383	V
MAIN Current Limit		550	800	1200	mA
	I _{LOAD} = 1mA		1		
MAIN Dropout Voltage	I _{LOAD} = 300mA		210	330	mV
	I _{LOAD} = 500mA		350	595	
SDIG Output Voltage	I _{LOAD} = 100µA to 200mA, V _{IN} = 3.6V to 5.5V	3.218	3.3	3.383	V
SDIG Current Limit		525	718	900	mA
	I _{LOAD} = 1mA		0.75		
SDIG Dropout Voltage	$I_{LOAD} = 200 \text{mA}$		170	300	mV
	$I_{LOAD} = 500 \text{mA}$		525	1010	
SDIG Reverse Leakage Current	$V_{SDIG} = 5.5V, V_{ENSD} = V_{IN} = 0V$		7	15	μA
COR2 Output Voltage	$I_{LOAD} = 100 \mu A$ to 50mA, $V_{IN} = 3.6V$ to 5.5V	1.755	1.8	1.845	V
COR2 Current Limit		65	98	150	mA
COR1 PWM BUCK					1
COR1 Output Voltage Accuracy	CV = high (MAX8594A)	1.743	1.8	1.855	V
	CV = high (MAX8594) or CV = low (MAX8594A)	1.259	1.3	1.340	
	CV = low (MAX8594)	0.972	1	1.023	
	$I_{LXC} = -180 \text{mA}$		0.70	1.34	Ω
p-Channel On-Resistance	I _{LXC} = -180mA, V _{PV} = 3.1V		0.8	1.58	
	I _{LXC} = 180mA		0.25	0.46	_
n-Channel On-Resistance	I _{LXC} = 180mA, V _{PV} = 3.1V		0.30	0.53	Ω
p-Channel Current-Limit Threshold		-0.500	-0.75	-0.925	А
n-Channel Current-Limit Threshold		-0.50	-0.72	-0.92	А
Minimum On and Off Times	ton(min)		0.1		
Minimum On- and Off-Times	toff(MIN)		0.1		μs
LXC Leakage Current	$V_{LXC} = 0V, V_{ENC1} = 0V$	-10	+0.1	+10	μA
REF AND RESET OUTPUT		·			
REF Voltage Accuracy	$I_{\text{REF}} = 0.1 \mu A$	1.236	1.25	1.264	V
REF Line Regulation	3.1V < V _{IN} < 5.5V, I _{REF} = 0.1µA		0.1	3	mV
REF Load Regulation	0.1μA < I _{REF} < 10μA		1	3	mV
RS Deassert Threshold for COR1	CV = low (MAX8594A), CV = low or CV = high (MAX8594)	88.00	90	93.25	%
Rising (Note 1)	CV = high (MAX8594A)	67.0	69	72.7	
		_			L

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{IN} = V_{PV} = V_{ENSD} = V_{ENC2} = V_{ENL} = V_{ENC1} = V_{DBI} = V_{LBI} = V_{CV} = 4.0V$, **T_A = 0°C to +85°C**, unless otherwise noted. Typical values are at T_A = +25°C.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
	CV = low or CV = high (MAX8594),		80		
RS Assert Threshold	CV = low (MAX8594A)				%
	CV = high (MAX8594A)		62.5		
RS Deassert Delay		10	20	30	ms
RS Assert Delay	50mV overdrive		5		μs
LCD					
LXL Voltage Range				28	V
LXL Current Limit	$L1 = 10\mu H$	195	235	275	mA
LXL On-Resistance			1.7		Ω
LXL Leakage Current	$V_{LXL} = 28V$		0.2	2	μΑ
Maximum LXL On-Time		2	3	4	μs
Minimum I.VI. Off Times	V _{LFB} > 1.1V	0.8	1	1.2	
Minimum LXL Off-Time	V _{LFB} < 0.8V (soft-start)	3.9	5	6.0	μs
LFB Feedback Threshold		1.229	1.25	1.270	V
LFB Input Bias Current	$V_{LFB} = 1.3V$		5	50	nA
SW Off-Leakage Current	$V_{SW} = 0V, V_{PV} = 5.5V, V_{ENL} = 0V$		0.01	1	μA
SW PMOS On-Resistance			1	1.5	Ω
SW PMOS Peak Current Limit			700		mA
SW PMOS Average Current Limit			300		mA
Soft-Start Time	$C_{SW} = 1 \mu F$		0.13		ms
LOGIC					
EN_, CV Input Low Level	V _{IN} = 3.1V to 5.5V			0.35	V
EN_, CV Input High Level	V _{IN} = 3.1V to 5.5V	1.4			V
EN_, CV Input Leakage Current			0.01	1	μA
RS, LBO, DBO Output Low Level	Sinking 1mA, V _{IN} = 2.5V		0.02	0.1	V
DBO Output Low Level	Sinking 100µA, V _{IN} = 1.0V		0.02	0.1	V
RS, LBO, DBO Output High Leakage	V _{OUT} = 5.5V, V _{IN} = 5.5V			1	μA
THERMAL PROTECTION		•			•
Thermal-Shutdown Temperature	Rising temperature		+160		°C
Thermal-Shutdown Hysteresis			15		°C

ELECTRICAL CHARACTERISTICS

 $(V_{IN} = V_{PV} = V_{ENSD} = V_{ENC2} = V_{ENL} = V_{ENM} = V_{ENC1} = V_{DBI} = V_{LBI} = 4.0V, T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C, \text{ unless otherwise noted.}) (Note 2)$

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
GENERAL		•			•
IN, PV Voltage Range		3.1		5.5	V
VIN Complete Shutdown	$V_{\text{DBI}} = V_{\text{IN}}, V_{\text{IN}}$ falling	2.93		3.06	
Threshold	V _{DBI} = V _{IN} , V _{IN} rising	3.135		3.525	V
V _{DBI} Complete Shutdown	V _{DBI} falling	1.228		1.264	V
Threshold	V _{DBI} rising	1.306		1.478	V
	V _{LBI} rising	1.228		1.264	V
V _{LBI} LBO Threshold	V _{LBI} falling	1.103		1.140	V
VIN LBO Threshold	$V_{LBI} = V_{IN}, V_{IN}$ falling	3.248		3.366	V
VIN LBO ITTreshold	$V_{LBI} = V_{IN}, V_{IN}$ rising	3.609		3.744	V
DRI Input Dual Mada Thrashold	Preset mode, V _{IN} = 2.9V	V _{IN} - 0.3			v
DBI Input Dual-Mode Threshold	ADJ mode, V _{IN} = 2.9V			V _{IN} - 1.25	V
LBI Input Dual-Mode Threshold with Respect to IN	Preset mode, V _{IN} = 3.2V	V _{IN} - 0.3			v
	ADJ mode, V _{IN} = 3.2V			V _{IN} - 1.25	V
DBI Complete Shutdown Input Program Range	V _{IN} falling	3.0		5.5	V
DBI Input Bias Current	V _{DBI} = 1.25V	-50		+50	nA
LBI Input Bias Current	$V_{LBI} = 1.25V$	-50		+50	nA
	Shutdown (DBI remains on, REF off), $V_{IN} = V_{PV} = V_{DBI} = V_{LBI} = 2.7V$			10	
IN, PV Operating Current	All off (REF on)			55	μA
	All on, LXL, LXC not switching			180	
	Main on, no load			75	
IN Operating Current	Main on, no load, COR1 on, LXC not switching			110	
IN Operating Current	All on except LCD, $V_{ENL} = 0V$, LXL and LXC not switching			160	μA
LDOs					
MAIN, SDIG Soft-Start Time	Ramp ILIM from 0% to 100%	300		1200	μs
MAIN Output Voltage	$I_{LOAD} = 100\mu A$ to 300mA, $V_{IN} = 3.6V$ to 5.5V	3.209		3.383	V
MAIN Current Limit		550		1230	mA
	I _{LOAD} = 300mA			330	mV
MAIN Dropout Voltage	$I_{LOAD} = 500 \text{mA}$			595	mv

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{IN} = V_{PV} = V_{ENSD} = V_{ENC2} = V_{ENL} = V_{ENM} = V_{ENC1} = V_{DBI} = V_{LBI} = 4.0V, T_{A} = -40^{\circ}C to +85^{\circ}C, unless otherwise noted.) (Note 2)$

PARAMETER	CONDITIONS	MIN 1	YP MAX	UNITS
SDIG Output Voltage	I _{LOAD} = 100µA to 200mA, V _{IN} = 3.6V to 5.5V	3.218	3.383	V
SDIG Current Limit		485	900	mA
	I _{LOAD} = 200mA		300	
SDIG Dropout Voltage	I _{LOAD} = 500mA		1250	mV
SDIG Reverse Leakage Current	$V_{SDIG} = 5.5V, V_{ENSD} = V_{IN} = 0V$		15	μA
COR2 Output Voltage	$I_{LOAD} = 100\mu A \text{ to } 50 \text{mA}, V_{IN} = 3.6 \text{V to } 5.5 \text{V}$	1.750	1.845	V
COR2 Current Limit		60	150	mA
COR1 PWM BUCK				
	CV = high (MAX8594A)	1.743	1.855	
COR1 Output Voltage Accuracy	CV = high (MAX8594) or CV = low (MAX8594A)	1.255	1.340	V
	CV = low (MAX8594)	0.969	1.023	1
	I _{LXC} = -180mA		1.34	
p-Channel On-Resistance	I _{LXC} = -180mA, V _{PV} = 3.1V		1.58	Ω
	I _{LXC} = 180mA		0.46	
n-Channel On-Resistance	I _{LXC} = 180mA, V _{PV} = 3.1V		0.53	Ω
p-Channel Current-Limit Threshold		-0.460	-0.925	А
n-Channel Current-Limit Threshold		-0.46	-0.92	A
LXC Leakage Current	$V_{PV} = 5.5V, V_{LXC} = 0V \text{ or } V_{PV}, V_{ENC1} = 0V$	-10	+10	μA
REF AND RESET OUTPUT				
REF Voltage Accuracy	$I_{\text{REF}} = 0.1 \mu A$	1.229	1.264	V
REF Line Regulation	3.1V < V < 5.5V, I _{REF} = 0.1μA		3	mV
REF Load Regulation	0.1μA < I _{REF} < 10μA		3	mV
RS Deassert Threshold for COR1	CV = low or CV = high (MAX8594), CV = low (MAX8594A)	88.00	93.25	%
Rising (Note 1)	CV = high (MAX8594A)	67.0	72.7	
RS Deassert Delay		10	30	ms
LCD				
LXL Voltage Range			28	V
LXL Current Limit	L1 = 10µH	180	280	mA
LXL Leakage Current	$V_{LXL} = 28V$		2	μA
Maximum LXL On-Time		2	4	μs
Minimum LXL Off-Time	V _{LFB} > 1.1V	0.8	1.2	μs
	V _{LFB} < 0.8V (soft-start)	3.9	6.0	μo
LFB Feedback Threshold		1.223	1.270	V
LFB Input Bias Current	$V_{LFB} = 1.3V$		50	nA
SW Off-Leakage Current	$V_{SW} = 0V$, $V_{PV} = 5.5V$, $V_{ENL} = 0V$		1	μA
SW PMOS On-Resistance			1.5	Ω

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{IN} = V_{PV} = V_{ENSD} = V_{ENC2} = V_{ENL} = V_{ENM} = V_{ENC1} = V_{DBI} = V_{LBI} = 4.0V, T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C, \text{ unless otherwise noted.}) (Note 2)$

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
LOGIC					
EN_, CV Input Low Level	V _{IN} = 3.1V to 5.5V			0.35	V
EN_, CV Input High Level	V _{IN} = 3.1V to 5.5V	1.4			V
EN_, CV Input Leakage Current				1	μΑ
RS, LBO, DBO Output Low Level	Sinking 1mA, V _{IN} = 2.5V			0.1	V
DBO Output Low Level	Sinking 100µA, V _{IN} = 1.0V			0.1	V
RS, LBO, DBO Output High Leakage	V _{OUT} = 5.5V, V _{IN} = 5.5V			1	μA

Note 1: The reset trip point tracks the COR1 voltage. For example, a minimum reset spec does not occur with a maximum COR1 spec, and a minimum COR1 spec does not occur with a maximum reset spec.

Note 2: Specifications to -40°C are guaranteed by design, not production tested.

Typical Operating Characteristics

(Circuit of Figure 2, $V_{IN} = 4V$, $T_A = +25^{\circ}C$, unless otherwise noted.)



Typical Operating Characteristics (continued)

(Circuit of Figure 2, $V_{IN} = 4V$, $T_A = +25^{\circ}C$, unless otherwise noted.)



Typical Operating Characteristics (continued)

(Circuit of Figure 2, $V_{IN} = 4V$, $T_A = +25^{\circ}C$, unless otherwise noted.)













LCD OUTPUT VOLTAGE vs. INPUT VOLTAGE





Typical Operating Characteristics (continued)

(Circuit of Figure 2, $V_{IN} = 4V$, $T_A = +25^{\circ}C$, unless otherwise noted.)







RS AND COR1 RESPONSE TO ENC1







Typical Operating Characteristics (continued)

(Circuit of Figure 2, $V_{IN} = 4V$, $T_A = +25^{\circ}C$, unless otherwise noted.)













Pin Description

PIN	NAME	FUNCTION
1	SDIG	3.3V, 500mA LDO Output for Secure-Digital Card Slot. SDIG has reverse current protection so SDIG can be biased when no power is present at IN. SDIG output turns off when V _{IN} is below the DBI threshold, ENSD goes low, or MAIN is out of regulation. When SDIG turns off, the output is discharged at a rate depending on the load and the internal feedback resistors (typically 1.3M Ω).
2	IN	Input Voltage to the MAX8594/MAX8594A. Bypass IN to GND with a 1µF ceramic capacitor.
3	RS	Reset Output. $\overline{\text{RS}}$ is an active-low, open-drain output that goes high impedance 20ms (typ) after COR1 is in regulation. COR1 does not turn on until MAIN is in regulation. If MAIN falls out of regulation, COR1 turns off and $\overline{\text{RS}}$ goes low. If MAIN is still in regulation, then $\overline{\text{RS}}$ goes low when V _{IN} is below the DBI threshold. $\overline{\text{RS}}$ goes low when ENC1 is low.
4	LBO	Low-Battery Detector Open-Drain Output. \overline{LBO} is an active-low, open-drain output that goes high impedance when V _{IN} is greater than both the DBI and LBI thresholds. \overline{LBO} goes low when V _{IN} falls below the LBI threshold.
5	DBO	Dead-Battery Detector Open-Drain Output. When V _{IN} is below the DBI threshold, both $\overline{\text{DBO}}$ and $\overline{\text{LBO}}$ go low, all outputs shut down, and the MAX8594/MAX8594A enter the lowest possible quiescent-current state. Once this occurs, MAIN does not turn back on until both V _{IN} exceeds the DBI threshold and ENM = high. $\overline{\text{DBO}}$ is an active-low, open-drain output that goes high impedance when V _{IN} exceeds the DBI threshold.
6	DBI	Dead-Battery Detector. DBI remains active at all times. If $DBI = IN$, the DBI threshold is 3.0V when IN is falling and 3.3V when rising. The DBI threshold can also be adjusted to other values by connecting DBI to a resistor voltage-divider. Also see the \overline{DBO} description.
7	LBI	Low-Battery Detector. If LBI = IN, the LBI threshold is $3.33V$ when IN is falling and $3.7V$ when rising. The LBI threshold can also be adjusted to other values by connecting LBI to a resistor voltage- divider. Also see the LBO description.
8	CV	Selects 1V or 1.3V COR1 Output Voltage for MAX8594, and 1.3V or 1.8V COR1 for MAX8594A. Drive CV high or connect to IN for a 1.3V COR1 output (1.8V COR1 for MAX8594A). Drive CV low or connect to GND for a 1V COR1 output (1.3V COR1 for MAX8594A).
9	ENM	Enable Input for MAIN. No other outputs turn on until MAIN is in regulation. If MAIN is pulled out of regulation, all other outputs turn off and $\overline{\text{RS}}$ goes low. MAIN cannot be activated when V _{IN} is below the DBI threshold.
10	GND	Ground
11	REF	1.25V 1% Reference. Bypass REF with a 0.1 μF capacitor to GND. REF is enabled when V _{IN} is greater than the DBI threshold. REF is off when V _{IN} is below the DBI threshold.
12	LFB	LCD Feedback Input. Connect LFB to a resistor-divider network between the LCD output and GND. The feedback threshold is 1.25V. LCD turns off when V_{IN} is below the DBI threshold, when ENL goes low, or when MAIN is out of regulation. When off, the LCD output is discharged at a rate depending on the load and the external feedback resistors (typically 2.4M Ω).
13	ENL	Enable Input for LCD (Boost Regulator). Drive ENL high to activate the LCD boost. Drive ENL low to shut down the LCD output. The LCD converter cannot be activated when V_{IN} is below the DBI threshold or before MAIN is in regulation.
14	LXL	LCD Boost Switch. Connect LXL to a boost inductor and Schottky diode. See Figure 1.



_Pin Description (continued)

PIN	NAME	FUNCTION
15	SW	LCD True-Shutdown Switch Output. SW is the power source for the LCD boost inductor. SW turns on when ENL is high. For best efficiency, bypass SW with a 4.7µF capacitor to GND. SW is disconnected from PV when LCD is shut down.
16	PV	Power Input for COR1 Buck Converter and LCD True-Shutdown Switch. Connect IN to PV.
17	PGND	Power Ground
18	LXC	COR1 Switching Node. Connect LXC to the COR1 inductor. See Figure 1.
19	ENC1	Enable Input for Primary Core Buck Converter (COR1). Drive ENC1 high to turn on COR1 and low to turn off. COR1 cannot be activated if V_{IN} is below the DBI threshold or before MAIN is in regulation.
20	ENSD	Enable Input for Secure Digital Card (SDIG). Drive ENSD low to turn off SDIG and high to turn on. SDIG cannot be activated when V _{IN} is below the DBI threshold or before MAIN is in regulation.
21	COR1	Feedback Sense Input for COR1 Output. COR1 turns off when V _{IN} is below the DBI threshold, when ENC1 goes low, or when MAIN is out of regulation. When off, the output is discharged by LXC through an internal $1M\Omega$ (typ) resistor.
22	ENC2	Enable Input for Secondary Core LDO (COR2). Drive ENC2 high to turn on COR2 and low to turn off. COR2 cannot be activated when V_{IN} is below the DBI threshold or before MAIN is in regulation. COR2 can be activated when V_{IN} is greater than the DBI threshold and MAIN is in regulation.
23	COR2	1.8V, 50mA LDO Output for Secondary Core. COR2 turns off when V _{IN} is below the DBI threshold, when ENC2 goes low, or when MAIN is out of regulation. The COR2 output is discharged at a rate depending on the load and the internal feedback resistors (typically 700k Ω).
24	MAIN	3.3V, 500mA LDO Output for Main Supply. MAIN output turns off when V _{IN} is below the DBI threshold or when ENM goes low. When off, the output is discharged at a rate depending on the load and the internal feedback resistors ($1.3M\Omega$ typ).
	EP	Exposed Pad. Connect to ground for enhanced power dissipation.



Figure 1. Typical Application Circuit with Charger

MAX8594/MAX8594A



MAX8594/MAX8594A

__Detailed Description

COR1 Step-Down DC-DC Converter

The COR1 regulator is a proprietary hysteretic PWM control step-down converter that supplies up to 400mA. The output voltage is set to either 1V or 1.3V by CV for the MAX8594 and 1.3V or 1.8V for the MAX8594A.

Under moderate to heavy loading, COR1 operates in a low-noise PWM mode with constant frequency and modulated pulse width. Switching harmonics generated by fixed-frequency operation are consistent and easily filtered. With light loads (<30mA), COR1 operates in an efficiency-enhanced Idle Mode[™] during which the converter switches only as needed to service the load.

Linear Regulators

Power for main logic, a SD card slot, and CODEC are provided by three LDOs:

- MAIN—Provides 3.3V at a guaranteed 500mA with a typical current limit of 800mA.
- SDIG—Provides 3.3V at a guaranteed 500mA for SD cards with a typical current limit of 718mA.
- COR2—Provides 1.8V at a guaranteed 50mA for a CODEC core with a typical current limit of 98mA.

Note that it may not be possible to draw the full rated current of MAIN and SDIG at all operating input voltages due to the dropout limitations of those regulators. The typical dropout resistance of the MAIN regulator is 0.7 Ω (350mV drop at 500mA), and the typical dropout resistance of the SDIG regulator is 0.85 Ω (525mV drop at 500mA).

All voltage outputs have separate enable inputs (ENM, ENL, ENSD, ENC1, and ENC2); however, no other output turns on until MAIN is in regulation. MAIN cannot be activated until V_{IN} exceeds the DBI threshold. When SDIG is turned off, reverse current is blocked so the SDIG output can be biased with an external source when no power is present at IN. Leakage current is typically 3μ A with 3.3V at SDIG.

LCD DC-DC Boost

The MAX8594/MAX8594A include a low-current, highvoltage boost DC-DC converter for LCD bias. This circuit can output up to 28V and is adjustable with either an analog or PWM control signal using external components.

SW provides an input-power disconnect for the LCD when ENL is low (off). The input-power disconnect

function is ideal for applications that require the output voltage to fall to 0V in shutdown (True Shutdown). If True Shutdown is not required, the SW switch can be bypassed by connecting the boost inductor directly to PV and removing the bypass cap on SW (C7 in Figure 1).

System Sleep

All regulated outputs turn off when V_{DBI} < 1.25V (or V_{IN} = 3.0V if DBI = IN, Figure 1). The MAX8594/MAX8594A resume normal operation when V_{DBI} > 1.375V (or V_{IN} = 3.3V if DBI = IN, Figure 1).

Reset Output (RS)

Reset $\overline{\text{RS}}$ asserts when COR1 falls 20% below its set level (38% for 1.8V setting in the MAX8594A). $\overline{\text{RS}}$ is an open-drain, active-low output. Connect a pullup resistor from $\overline{\text{RS}}$ to the logic supply of the gate receiving the reset signal. $\overline{\text{RS}}$ deasserts a minimum of 10ms after the COR1 output is in regulation. Upon application of valid input power, the MAIN output activates first (if ENM = high) followed by other outputs (if EN_ = high). Power and output sequencing are shown in Figure 3.



Figure 3. Power Sequence for Rising and Falling Input Voltage. Note that V_{IN} thresholds are for LBI and DBI connected to V_{IN} . Other thresholds can be set with resistors.



Power Sequencing

As VIN increases from 0V, sequencing is as follows:

- 1) The DBI comparator is always on. $\overline{\text{DBO}}$, $\overline{\text{LBO}}$, and $\overline{\text{RS}}$ are pulled low at approximately V_{IN} = 0.7V. MAIN, SDIG, COR1, COR2, and LCD are off.
- 2) When V_{IN} rises above the DBI threshold (3.3V if DBI = IN), DBO goes high impedance immediately and the part turns on. The MAIN LDO turns on if ENM = HIGH.
- When the MAIN output reaches 90% of its nominal voltage, or 2.97V, all other regulators turn on if they are enabled.
- 4) RS goes high impedance 20ms after COR1 reaches 90% of its nominal voltage (69% when 1.8V setting in the MAX8594A is used).
- 5) When V_{IN} rises above the LBI threshold (3.7V if LBI = IN), LBO goes high impedance.

As IN decreases, sequencing is as follows:

- 1) When V_{IN} falls to the LBO threshold (3.33V if LBI = IN), LBO is pulled to GND.
- 2) If V_{IN} falls to the DBI threshold (3.0V if <u>LBI</u> = IN) before the MAIN output falls to 2.838V, <u>DBO</u> and <u>RS</u> go low, all regulators turn off, and the part is shut down.
- 3) If the MAIN output falls below 86% of its nominal voltage (2.838V) before IN reaches the DBI threshold (3.0V if DBI = IN), RS is pulled to GND and all other outputs turn off, but MAIN remains on (in dropout) and DBO remains high until IN falls to the DBI threshold.

_Applications Information

COR1 Buck Output

COR1 Inductor

A 2.2µH inductor with a saturation current of at least 500mA is recommended. For lower load currents, the inductor current rating may be reduced. For maximum efficiency, the inductor's DC resistance should be as low as possible. Note that core materials differ among manufacturers and inductor types, resulting in variations in efficiency.

COR1 Capacitors

Ceramic input and output capacitors are recommended. For best stability over a wide temperature range, use capacitors with an X5R or X7R dielectric due to their low ESR and low temperature coefficient. The COR1 output capacitor C6 (Figure 1) is required to keep the output voltage ripple small; 2.2μ F is recommended for most applications.

Due to the pulsating nature of input current in a buck converter, a low-ESR input capacitor is required for input voltage filtering and to minimize interference with other circuits. The impedance of the input capacitor, C5 (Figure 1), should be kept very low at the switching frequency. A minimum value of 4.7μ F is recommended at PV for most applications. The input capacitor can be increased to further improve input filtering.

LDO Output Capacitors (MAIN, SDIG, COR2)

Capacitors are required at each LDO output of the MAX8594/MAX8594A for stable operation over the full load and temperature range. See Figure 1 for recommended capacitor values for each output. To reduce noise and improve load-transient response, larger output capacitors up to 10 μ F can be used. Surface-mount ceramic capacitors have very low ESR and are commonly available in values up to 10 μ F. X7R and X5R dielectrics are recommended. Note that some ceramic dielectrics, such as Z5U and Y5V, exhibit large capacitance and ESR variation with temperature and require larger than the recommended values to maintain stability overtemperature.

Setting LBI and DBI

The DBI and LBI inputs monitor input voltage (usually a battery) and trigger the DBO and LBO outputs. With LBI and DBI connected to IN, the LBI and DBI thresholds are internally set. For a rising input voltage, DBO goes high when V_{IN} exceeds 3.3V and LBO goes high when V_{IN} exceeds 3.7V. For a falling input voltage, LBO goes low when V_{IN} falls below 3.3V and DBO goes low when V_{IN} falls below 3.0V (see also the *Electrical Characteristics* table and Figure 3). Alternatively, the LBI and DBI thresholds can be set with external resistors as shown in Figures 4 and 5.





Figure 4. Setting the DBI and LBI Threshold with Three External Resistors

In Figure 4, one three-resistor-divider can set both DBI and LBI according to the following equations (shown for setting falling thresholds). Choose the lower resistor of the divider chain (R5 in Figure 4) to be between $100k\Omega$ and $250k\Omega$. The equations for the two upper resistor-dividers as a function of each (falling) threshold are:

$$R3 = R5 \times \frac{V_{LBFALL}}{1.125} \times \left(1 - \frac{1.25}{V_{DBFALL}}\right)$$

$$R4 = R5 \times \frac{1.25 \times V_{LBFALL}}{1.125 \times V_{DBFALL}} - 1$$

where V_{DBFALL} and V_{LBFALL} are the desired falling thresholds to trigger the DBO and LBO outputs, respectively. Once those thresholds are selected, the rising DBI and LBI thresholds are:

$$V_{\text{DBRISE}} = 1.375 \times \frac{\text{R3} + \text{R4} + \text{R5}}{\text{R4} + \text{R5}}$$

$$V_{\text{LBRISE}} = 1.25 \, \text{x} \frac{\text{R3} + \text{R4} + \text{R5}}{\text{R5}}$$



Figure 5. Setting the DBI and LBI Thresholds with Four Resistors

Alternately, LBI and DBI can be set with separate resistor-dividers. The resistor calculation is simpler and the two settings do not interact, but one more resistor is needed and battery drain is slightly higher due to the extra resistor load. Choose the lower resistor of each divider chain (R7 and R9 in Figure 5) to be between $100k\Omega$ and $250k\Omega$. The equations for upper resistordividers as a function of each (falling) threshold are:

$$R6 = R7 x \left(\frac{V_{DBFALL}}{1.25} - 1 \right)$$

$$R8 = R9 \times \left(\frac{V_{LBFALL}}{1.125} - 1\right)$$

where VDBFALL and VLBFALL are the desired falling thresholds to trigger the DBO and LBO outputs, respectively. Once those thresholds are selected, the rising DBI and LBI thresholds are:

$$V_{\text{DBRISE}} = 1.375 \times \frac{\text{R6} + \text{R7}}{\text{R7}}$$

$$V_{LBRISE} = 1.25 \times \frac{R8 + R9}{R9}$$

Note that the low-battery threshold should not be set below the dead-battery threshold because both DBO





Figure 6. Adjusting the Output Voltage with a DAC

and $\overline{\text{LBO}}$ are automatically driven low and the part is shut down when the DBI threshold is crossed (going low).

LCD Boost Output

LCD Inductor

The LCD boost is designed to operate with a wide range of inductor values (4.7µH to 150µH). Smaller inductance values typically offer smaller size for a given series resistance or saturation current. Smaller values cause LX to switch more frequently for a given load and can reduce efficiency at low load currents. Larger values reduce switching losses due to less frequent switching for a given load, but higher DC resistance can reduce efficiency. Note that for inductors larger than 43µH, the peak inductor current does not reach 250mA before the LXL maximum on-time (3µs) expires. This reduces output current but may be beneficial for light-load efficiency. A 10µH inductor provides a good balance and works well for most applications. The inductor's saturation current rating should be greater than the peak switching current (250mA).

LCD Diode

Schottky diodes rated at 250mA or more, such as the MBR0530 or Nihon EP05Q03L, are recommended. The diode reverse-breakdown voltage rating must be greater than the LCD output voltage.

LCD Capacitors

For most applications, use a ceramic $1\mu \dot{F}$ output capacitor. This typically provides a peak-to-peak output ripple of 30mV. In addition, bypass IN with $1\mu F$ and SW with 4.7 μF ceramic capacitors. An LCD feed-forward capacitor, connected from the output to LFB, improves stability over a wide range of battery voltages. A 47pF

capacitor is sufficient for most applications; however, the optimum value is affected by PC board layout.

Setting LCD Voltage

Adjust the output voltage by connecting a voltagedivider from the LCD output to LFB (see Figure 1). Select R2 between $10k\Omega$ and $200k\Omega$. Calculate R1 with the following equation:

$$R1 \!=\! R2x \! \left(\frac{V_{OUT}}{V_{LFB}} \!-\! 1 \right)$$

where $V_{LFB} = 1.25V$ and V_{OUT} can range from V_{IN} to 28V. The input bias current of LFB is typically only 5nA, allowing large-value resistors to be used. For less than 1% error, the current through R2 should be greater than 100 times the feedback input bias current (I_{LFB}).

LCD Adjustment

The LCD boost output can be digitally adjusted by either a DAC or PWM signal.

DAC Adjustment

Adding a DAC and a resistor, R_D, to the divider circuit (Figure 6) provides DAC adjustment of V_{OUT}. Ensure that V_{OUT}(MAX) does not exceed the LCD panel rating. The output voltage (V_{OUT}) as a function of the DAC voltage (V_{DOUT}) is calculated using the following formula:

$$V_{OUT} = 1.25 x \left(1 + \left(\frac{R1}{R2} \right) \right) + \frac{(1.25 - V_{DOUT}) x R1}{R_D}$$

Using PWM Signals

Many μ Ps have the ability to create PWM outputs. These are digital outputs, based on either 16-bit or 8-bit counters, with a programmable duty cycle. In many applications, they are suitable for adjusting the output of the MAX8594/MAX8594A as seen in Figure 7.

The circuit consists of the PWM source, capacitor C11, and resistors R_D and R_W . To analyze the transfer function of the PWM circuit, it is easiest to first simplify it to its Thevenin equivalent. The Thevenin voltage is calculated using the following formula:

$$V_{\text{THEV}} = (D \times V_{\text{OH}}) + (1 - D) \times V_{\text{OL}}$$

where D is the duty cycle of the PWM signal, V_{OH} is the PWM output high level (often 3.3V), and V_{OL} is the PWM output low level (usually 0V). For CMOS logic, this equation simplifies to:

$V_{THEV} = D \times V_{DD}$

where V_{DD} is the logic-high output voltage of the PWM output. The Thevenin impedance is the sum of resistors R_W and R_D :

$$R_{THEV} = R_D + R_W$$

The output voltage (V_{OUT}) as a function of the PWM average voltage (V_{THEV}) is:

$$V_{OUT} = 1.25 \, \text{x} \left(1 + \left(\frac{\text{R1}}{\text{R2}} \right) \right) + \frac{\left(1.25 - V_{\text{THEV}} \right) \text{x} \text{R1}}{\text{R}_{\text{THEV}}}$$

When using the PWM adjustment method, R_D isolates the capacitor from the feedback loop of the MAX8594/MAX8594A. The cutoff frequency of the low-pass filter is defined as:

$$f_{\rm C} = \frac{1}{2 \times \pi \times R_{\rm THEV} \times C_{11}}$$

The cutoff frequency should be at least two decades below the PWM frequency to minimize the induced AC ripple at the output.

An important consideration is the turn-on transient created by the initial charge on filter capacitor C11. This capacitor forms a time constant with R_{THEV} , causing the output to initialize at a higher than intended voltage. This overshoot is minimized by scaling R_D as high as possible compared to R1 and R2. Alternatively, the μ P can briefly keep the LCD disabled until the PWM voltage has had time to stabilize.



Figure 7. PWM-Controlled LCD Bias

PC Board Layout and Grounding

Careful PC board layout is important for minimizing ground bounce and noise. Keep the MAX8594/ MAX8594A's ground pin and the ground leads of the input and output capacitors less than 0.2in (5mm) apart. In addition, keep all connections to LFB, COR1, LXC, and LXL as short as possible. In particular, external feedback resistors should be as close to LFB as possible. To minimize output voltage ripple and to maximize output power and efficiency, use a ground plane and solder PGND and exposed pad directly to the ground plane. Refer to the MAX8594 evaluation kit for a layout example.

Thermal Considerations

In most applications, the circuit is located on a multilayer board and full use of the four or more layers is recommended. For heat dissipation, connect the exposed backside pad of the thin QFN package to a large ground plane, preferably on a surface of the board that receives good airflow. Typical applications use multiple ground planes to minimize thermal resistance. Avoid large AC currents through the ground plane.



Chip Information

TRANSISTOR COUNT: 3436 PROCESS: BICMOS

_Pin Configuration



MAX8594/MAX8594A

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <u>www.maxim-ic.com/packages</u>.)



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